CMOS Digital Integrated Circuits Silicon Monolithic

# TC7SBL66CFU,TC7SBL384CFU

#### 1. Functional Description

Low-Capacitance Single Bus Switch (analog)

#### 2. General

The TC7SBL66CFU and TC7SBL384CFU are a Low Voltage / Low Capacitance CMOS single Bus Switch. The low On-resistance of the switch allows connections to be made with minimal propagation delay time. The TC7SBL66CFU requires the output enable (OE) input to be set low to place the output into the high impedance state, whereas the TC7SBL384CFU requires the output enable ( $\overline{OE}$ ) input to be set high to place the output into the high impedance.

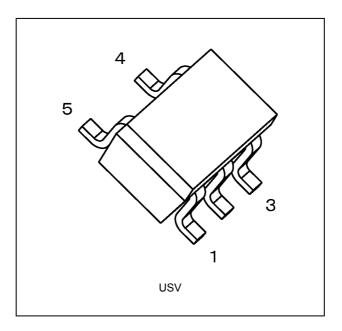
All inputs are equipped with protection circuits against static discharge.

#### 3. Features

- (1) Wide operating temperature range:  $T_{opr}$  = -40 to 125 °C (Note 1)
- (2) Operating voltage:  $V_{CC}$  = 1.65 to 3.6 V
- (3) ON capacitance:  $C_{I/O}$  = 7 pF Switch On (typ.) @V<sub>CC</sub> = 3.0 V
- (4) ON resistance:  $R_{ON} = 5.5 \Omega$  (typ.)  $@V_{CC} = 3 V$ ,  $V_{IS} = 0 V$
- (5) Power-down protection for inputs (OE and  $\overline{OE}$ , I/O)
- (6) Package: USV

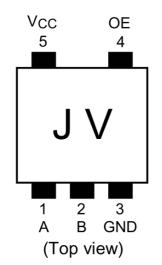
Note 1: For devices with the ordering part number ending in (CT. T<sub>opr</sub> = -40 to 85 °C for the other devices.

#### 4. Packaging

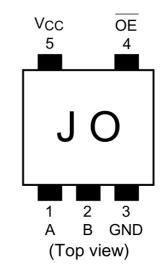


# 5. Pin Assignment

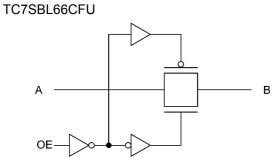
### TC7SBL66CFU



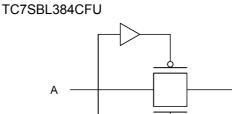
TC7SBL384CFU



# 6. Block Diagram







OE -

# 7. Principle of Operation

### 7.1. Truth Table

Inputs OE (TC7SBL66CFU)	Inputs OE (TC7SBL384CFU)	Function
Н	L	A port = B port
L	Н	Disconnect

В

2

#### 8. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Characteristics		Note	Rating	Unit
Supply voltage		V <sub>CC</sub>		-0.5 to 4.6	V
Input voltage (OE, OE)		V <sub>IN</sub>		-0.5 to 4.6	V
Switch I/O voltage	$V_{CC} = 0$ V or Switch = Off	Vs		-0.5 to 4.6	V
	Switch = On			-0.5 to V <sub>CC</sub> +0.5	]
Clamp diode current		I <sub>IK</sub>		-50	mA
Switch I/O current		I <sub>S</sub>		50	mA
Power dissipation		PD		200	mW
V <sub>CC</sub> /ground current		I <sub>CC</sub> /I <sub>GND</sub>		±100	mA
Storage temperature		T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### 9. Operating Ranges (Note)

Characteristics		Symbol	Note	Rating	Unit
Supply voltage		V <sub>CC</sub>		1.65 to 3.6	V
Input voltage (OE, OE)		V <sub>IN</sub>		0 to 3.6	V
Switch I/O voltage	$V_{CC} = 0$ V or Switch = Off	Vs		0 to 3.6	V
	Switch = On			0 to V <sub>CC</sub>	
Operating temperature		T <sub>opr</sub>	(Note 1)	-40 to 125	°C
			(Note 2)	-40 to 85	
Input rise time		dt/dv		0 to 10	ns/V
Input fall time				0 to 10	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused control inputs must be tied to either V<sub>CC</sub> or GND.

Note 1: For devices with the ordering part number ending in (CT.

Note 2: For devices except those with the ordering part number ending in (CT.

### **10. Electrical Characteristics**

### 10.1. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage (OE, OE)	V <sub>IH</sub>		_	1.65 to 3.6	$0.7  imes V_{CC}$		—	V
Low-level input voltage (OE, OE)	V <sub>IL</sub>		—	1.65 to 3.6	—	—	$0.3 \times V_{CC}$	V
Input leakage current (OE, OE)	I <sub>IN</sub>		V <sub>IN</sub> = 0 to 3.6 V	1.65 to 3.6		_	±1.0	μA
Power-OFF leakage current	I <sub>OFF</sub>		OE, <del>OE</del> , A, B = 0 to 3.6 V	0	—	_	10	μA
Switch OFF-state leakage current	I <sub>SZ</sub>		A, B = 0 to $V_{CC}$ , <u>OE</u> = GND(TC7SBL66CFU), <u>OE</u> = $V_{CC}$ (TC7SBL384CFU)	1.65 to 3.6	—	_	±1.0	μΑ
ON-resistance	R <sub>ON</sub>	(Note 1), (Note 2)	V <sub>IS</sub> = 0 V, I <sub>IS</sub> = 30 mA	3.0	—	5.5	10	Ω
			V <sub>IS</sub> = 3.0 V, I <sub>IS</sub> = 30 mA	3.0	—	10	16	
			V <sub>IS</sub> = 2.4 V, I <sub>IS</sub> = 15 mA	3.0	_	12	18	
			V <sub>IS</sub> = 0 V, I <sub>IS</sub> = 24 mA	2.3	—	6	10	
			V <sub>IS</sub> = 2.3 V, I <sub>IS</sub> = 24 mA	2.3	—	13	20	
			V <sub>IS</sub> = 2.0 V, I <sub>IS</sub> = 15 mA	2.3	—	15	21	
			V <sub>IS</sub> = 0 V, I <sub>IS</sub> = 4 mA	1.65	—	7	13	
			V <sub>IS</sub> = 1.65 V, I <sub>IS</sub> = 4 mA	1.65	—	18	27	
Quiescent supply current	I <sub>CC</sub>		V <sub>IN</sub> = V <sub>CC</sub> or GND, I <sub>OUT</sub> = 0 A	3.6	—		10	μA

Note 1: All typical values are at  $T_a = 25$  °C.

Note 2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (A or B) pins.

# 10.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Note	Test Condition	V <sub>CCB</sub> (V)	Min	Max	Unit
High-level input voltage (OE, OE)	V <sub>IH</sub>		—	1.65 to 3.6	$0.7 \times V_{CC}$	—	V
Low-level input voltage (OE, OE)	V <sub>IL</sub>		—	1.65 to 3.6	—	$0.3 \times V_{CC}$	V
Input leakage current (OE, OE)	I <sub>IN</sub>		V <sub>IN</sub> = 0 to 3.6 V	1.65 to 3.6	—	±10.0	μA
Power-OFF leakage current	I <sub>OFF</sub>		OE, $\overline{OE}$ , A, B = 0 to 3.6 V	0	_	40	μA
Switch OFF-state leakage current	I <sub>SZ</sub>		A, B = 0 to $V_{CC}$ , <u>OE</u> = GND(TC7SBL66CFU), <u>OE</u> = $V_{CC}$ (TC7SBL384CFU)	1.65 to 3.6	_	±10.0	μΑ
ON-resistance	R <sub>ON</sub>		V <sub>IS</sub> = 0 V, I <sub>IS</sub> = 30 mA	3.0	—	13	Ω
			V <sub>IS</sub> = 3.0 V, I <sub>IS</sub> = 30 mA	3.0	—	19	
			V <sub>IS</sub> = 2.4 V, I <sub>IS</sub> = 15 mA	3.0	—	21	
			V <sub>IS</sub> = 0 V, I <sub>IS</sub> = 24 mA	2.3	—	13	
			V <sub>IS</sub> = 2.3 V, I <sub>IS</sub> = 24 mA	2.3	_	23	
			V <sub>IS</sub> = 2.0 V, I <sub>IS</sub> = 15 mA	2.3	—	24	
			V <sub>IS</sub> = 0 V, I <sub>IS</sub> = 4 mA	1.65	—	16	
			V <sub>IS</sub> = 1.65 V, I <sub>IS</sub> = 4 mA	1.65	-	30	
Quiescent supply current	I <sub>CC</sub>		V <sub>IN</sub> = V <sub>CC</sub> or GND, I <sub>OUT</sub> = 0 A	3.6	—	40	μA

Note 1: All typical values are at  $T_a = 25$  °C.

Note 2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (A or B) pins.

# 10.3. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>	See Fig. 11.1, 11.2,	$\textbf{3.3}\pm\textbf{0.3}$	_	6	ns
			$2.5\pm0.2$	_	7	
			$1.8\pm0.15$	_	11	
Output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>	See Fig. 11.1, 11.2,	$3.3\pm 0.3$	_	6	ns
		Table 11.1.1	$2.5\pm0.2$	_	7	
			$\textbf{1.8}\pm\textbf{0.15}$	_	11	

### 10.4. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>	See Fig. 11.1, 11.2,	$\textbf{3.3}\pm\textbf{0.3}$	_	8	ns
		Table 11.1.1	$2.5\pm0.2$	_	9	
			1.8 ± 0.15	_	13	
Output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>	See Fig. 11.1, 11.2,	$\textbf{3.3}\pm\textbf{0.3}$	_	8	ns
		Table 11.1.1	$2.5\pm0.2$	_	9	
			1.8 ± 0.15	_	13	

#### 10.5. Capacitive Characteristics (Note) (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance (OE, OE)	C <sub>IN</sub>	$V_{IN} = 0 V$	3.0	4	pF
Switch terminal OFF-capacitance	C <sub>I/O</sub>	$\label{eq:observation} \begin{split} \underline{OE} &= GND(TC7SBL66CFU),\\ \overline{OE} &= V_{CC}(TC7SBL384CFU),\\ V_{IS} &= 0 \; V \end{split}$	3.0	3.5	pF
Switch terminal ON-capacitance	C <sub>I/O</sub>		3.0	7	pF

Note: Parameter guaranteed by design.

#### 11. AC Electrical Test Circuit

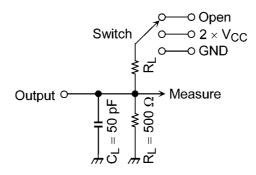


Fig. 11.1 AC Test Circuit

Table 11.1.1	Parameter for AC Test Circuit
--------------	-------------------------------

Parameter	Switch	
t <sub>PLZ</sub> , t <sub>PZL</sub>	$2 \times V_{CC}$	
t <sub>PHZ</sub> , t <sub>PZH</sub>	GND	

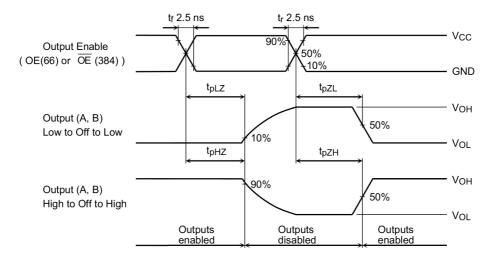


Fig. 11.2 AC Waveform tPLZ, tPHZ, tPZL, tPZH

### 12. Rise and Fall Time (t<sub>r</sub>/t<sub>f</sub>)

The  $t_{r(out)}$  and  $t_{f(out)}$  values of the output signals are affected by the CR time constant of the input, which consists of the switch terminal capacitance ( $C_{I/O}$ ) and the on-resistance ( $R_{ON}$ ) of the input.

In practice, the  $t_{r(out)}$  and  $t_{f(out)}$  values are also affected by the circuit's capacitance and resistance components other than the capacitance of TC7SBL66CFU, TC7SBL384CFU

The  $t_{r}\!/t_{f(out)}$  values can be approximated as follows.

(Figure 12.1, Table 12.1 shows the test circuit.)

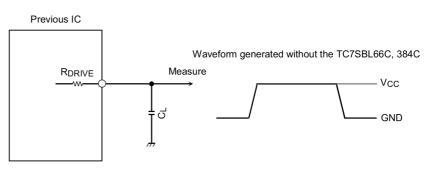
$$\label{eq:tr} \begin{split} t_r / t_{f(out)} \ (approx) = & \ (C_{I/O} + C_L) \ \cdot \ (R_{DRIVE} + R_{ON}) \ \cdot \ ln \ (((V_{OH} \cdot V_{OL}) \cdot V_M) \ / \ (V_{OH} \cdot V_{OL})) \end{split}$$
 Where,  $R_{DRIVE}$  is the output impedance of the previous-stage circuit.

Calculation example:

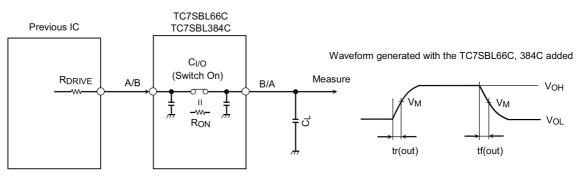
 $t_r/t_{f(out)}$  (approx) =  $\cdot$  (7 + 15) E  $\cdot$  12  $\cdot$  (120 + 5.5)  $\cdot$  ln (((3.0  $\cdot$  0)  $\cdot$  1.5) / (3.0  $\cdot$  0)) =  $\approx$ 1.9 ns

Calculation conditions:

 $V_{CC}$  = 3.0 V,  $C_L$  = 15 pF,  $R_{DRIVE}$  = 120  $\Omega$  (output impedance of the previous IC),  $V_M$  = 1.5 V ( $V_{CC}$ /2) Output of the previous IC = digital (i.e., high-level voltage =  $V_{CC}$ , low-level voltage = GND)



RDRIVE = output impedance of the previous IC



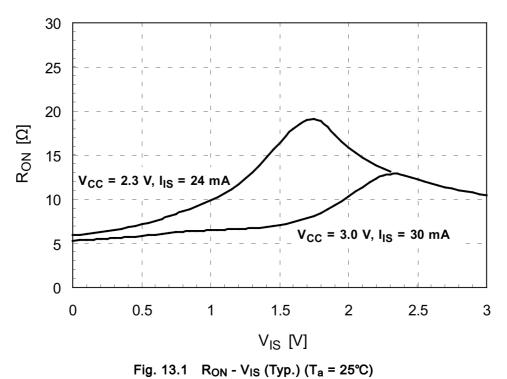
RDRIVE = output impedance of the previous IC

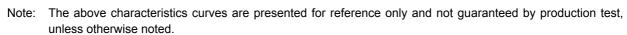
Fig. 12.1 Calculation Circuit

Characteristics	$V_{CC}$ = 3.3 $\pm$ 0.3 V	$V_{CC}$ = 2.5 $\pm$ 0.2 V	$V_{CC}$ = 1.8 $\pm$ 0.15 V
V <sub>M</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2

Table 12.1 Calculation Circuit

### 13. Characteristic (Note)

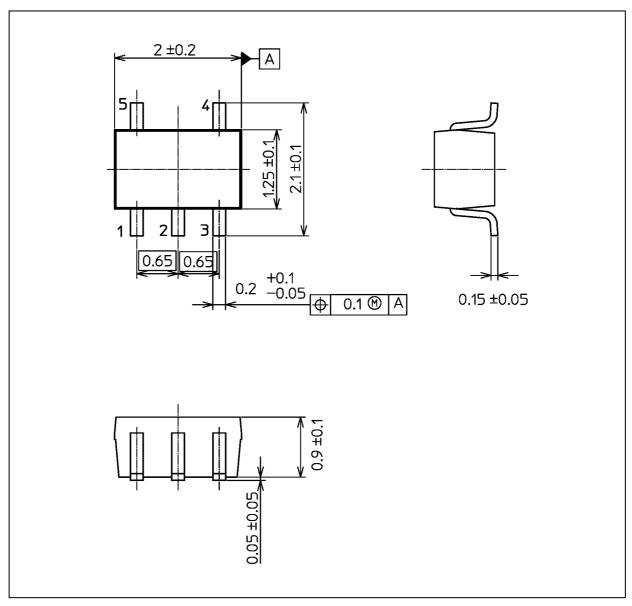






#### **Package Dimensions**

Unit: mm



Weight: 0.006 g (typ.)

	Package Name(s)
JEDEC: SOT-353	
Nickname: USV	

#### **RESTRICTIONS ON PRODUCT USE**

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE").

Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant.

IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your TOSHIBA sales representative or contact us via our website.

- · Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
  applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

#### TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION https://toshiba.semicon-storage.com/

单击下面可查看定价,库存,交付和生命周期等信息

>>Toshiba(东芝)